

## LINEAR INTEGRATED CIRCUITS

## DESCRIPTION

The Signetics NE501 is a direct-coupled broad-band amplifier fabricated within a monolithic silicon substrate by planar and epitaxial techniques. Typical applications include video amplifiers.

Application flexibility is provided by several external pin connections which adjust the amplifier characteristics to individual needs.

## FEATURES

- **ADJUSTABLE GAIN AND IMPEDANCE**

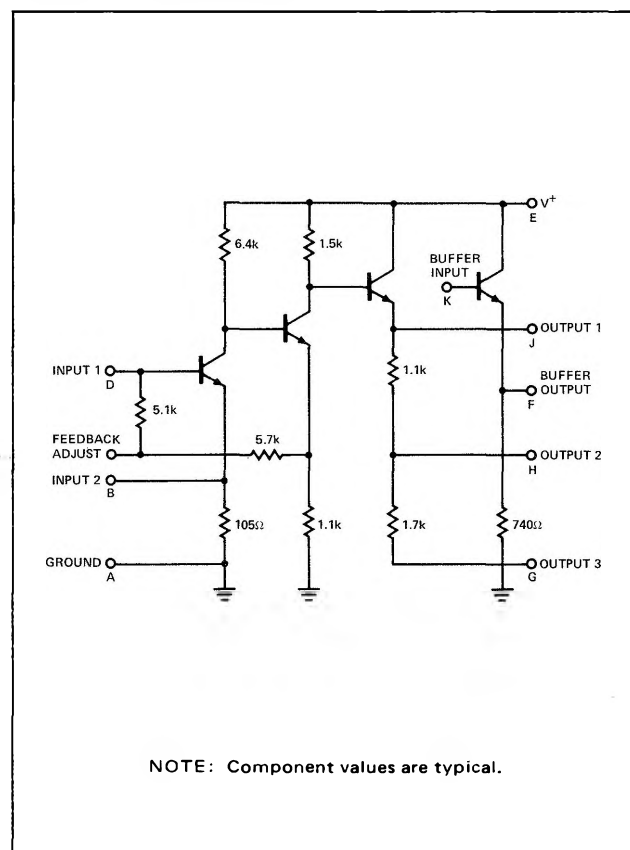
## CHARACTERISTICS

- **UNITY GAIN FREQUENCY – 150 MHz**
- **NOISE FIGURE – 5.0dB**
- **POWER DISSIPATION – 20mW**

### ABSOLUTE MAXIMUM RATINGS

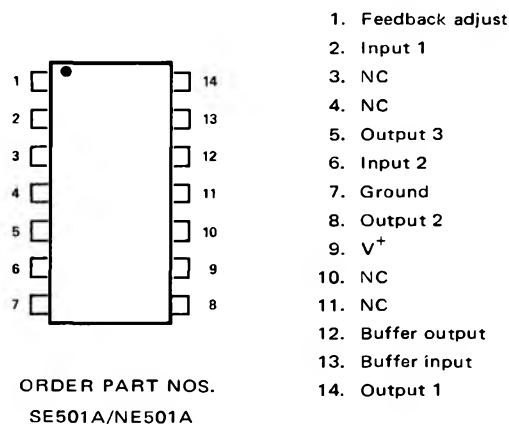
Voltage Applied	$V_{G,H,E,C}$	+8.0V
Voltage Applied	$V_B$	±3.0V
Voltage Applied	$V_{K,D}$	+4.0V
Current Rating	$I_{F,J}$	±30mA
Storage Temperature		-65°C to +150°C
Operating Temperature	NE501	0°C to +70°C
	SE501	-55°C to +125°C

### CIRCUIT SCHEMATIC

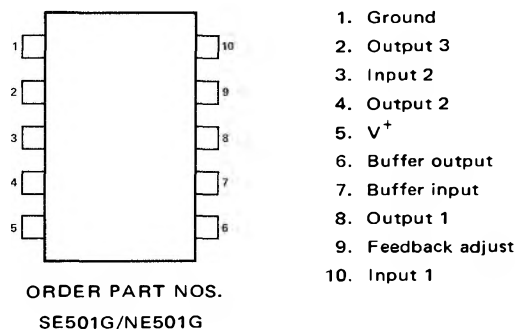


## PIN CONFIGURATIONS

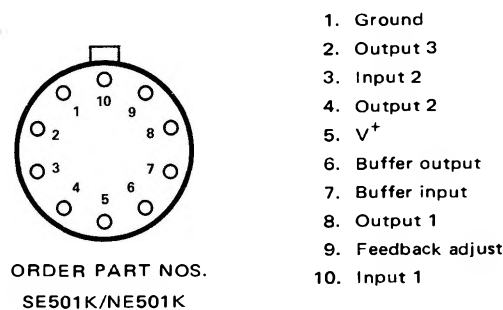
### A PACKAGE (Top View)



### G PACKAGE



### K PACKAGE



## ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITIONS	NE501			SE501			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
Voltage Gain	$f = 50 \text{ kHz}$ ; Notes 1, 2, 6	22.5	24	26.5	23	24	26	dB
Bandwidth (-3dB)	Notes 1, 2, 6	11			14			MHz
Unity Gain Frequency	$A_{V_O} = 0\text{dB}$ ; Notes 2, 6	100	150		100	150		MHz
Voltage Gain Stability	$f = 50 \text{ kHz}$ ; $T = 0^\circ\text{C}$ ; Notes 2, 6	-1.0						dB
	$f = 50 \text{ kHz}$ ; $T = +70^\circ\text{C}$ ; Notes 2, 6			+0.6				dB
	$f = 50 \text{ kHz}$ ; $T = -55^\circ\text{C}$ ; Notes 2, 6				-1.0			dB
	$f = 50 \text{ kHz}$ ; $T = +125^\circ\text{C}$ ; Notes 2, 6						+0.6	dB
Output Voltage	Notes 1, 2, 6, 9	0.71	1.0		0.71	1.0		$V_{\text{RMS}}$
Input Impedance	Notes 1, 6; $f = 50 \text{ kHz}$ ; $V_J = V_K$	470		1200	540		1100	$\Omega$
Output Impedance	Notes 1, 2; $f = 50 \text{ kHz}$ ; $V_D = \text{AC ground}$		12	18		12	18	$\Omega$
Output Impedance	Notes 1, 5; $f = 50 \text{ kHz}$ ; $V_D = \text{AC ground}$		25	65		25	50	$\Omega$
Power Dissipation				24			21	mW
Power Dissipation	$V_K = V_J$			60			53	mW
Pulse Response								
Delay Time	Notes 2, 6, 7			15			15	ns
Rise Time	Notes 2, 6, 7		12	20		12	16	ns
Noise Figure	$f = 100 \text{ kHz}$ ; $\text{BW} = 100 \text{ Hz}$ ; $Z_s = 500\Omega$		5.0	8.0				dB
	$f_c = 100 \text{ kHz}$ ; $\text{BW} = 100 \text{ Hz}$ ; $Z_s = 500\Omega$ , $V_J = V_K$					5.0	7.0	dB

(Notes: 3, 4, 5, 8) Standard Conditions:  $V_E = +6.0\text{V}$ ,  $V_A = 0\text{V}$ ,  $V_G = V_B$ ,  $T = +25^\circ\text{C}$  (except as noted)

## NOTES:

- Variations in this parameter depend on optional alternate connections as indicated in accompanying curves.
- Measured at Pin F, with Pins J and K connected.
- Pins not specifically referenced are left electrically open. All voltages are referenced to Pin A. Letter subscripts denote pins on circuit schematic.
- Positive current flow is defined as into the terminal referenced.
- Measured at Pin J.
- Load Resistance =  $600\Omega$ , capacitively coupled.
- Delay time is defined as the time interval between the 50% points of  $e_D$  and  $e_F$ . Rise time = 20% to 80% points of  $e_F$ . Input Pulse Characteristics: Amplitude = 25mV; PW = 100ns.
- See Signetics SURE Program Bulletin No. 5001 for definition of Acceptance test Sub-Groups. Sub-Group A-7 is used for the electrical end points for Linear Products.
- Total harmonic distortion less than 5% at  $e_O = 0.71 V_{\text{RMS}}$ .